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Applicant: Nayfeh et al.

Filing Date: February 2, 2000

Group: 1741

**U.S. PATENT DOCUMENTS**

Examiner Initial*	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
SW	5 3 0 8 8 0 4	05/03/1994	Lee	501	17	
	5 5 2 7 3 8 6	06/18/1996	Statz	106	481	
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	5 6 9 5 6 1 7	12/09/1997	Graiver et al.	204	157.41	
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	5 8 9 1 5 4 8	04/06/1999	Graiver et al.	428	98	
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Document Number	Date	Country	Class	Subclass	Translation	
					Yes	No

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SWC	Z. Yamani, W.H. Thompson, L. Abu Hassan, M.H. Nayfeh, "Ideal Anodization of Silicon", <i>Appl. Phys. Lett.</i> , Vol. 70,
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SWL	Z. Yamani, N. Rigakis, M.H. Nayfeh, "Excitation of Size Selected Nanocrystallites in Porous Silicon", <i>Appl. Phys. Lett.</i> , Vol. 72, No. 20, May 18, 1998, pp. 2556-58.
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